

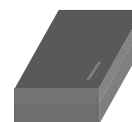
GNSS LOW NOISE AMPLIFIER

■ GENERAL DESCRIPTION

The NJG1155UX2 is a low noise amplifier GaAs MMIC designed for GNSS (Global Navigation Satellite Systems). The NJG1155UX2 is featured low noise figure, and operates from 1.5V to 3.3V single voltage. The NJG1155UX2 has stand-by mode to save the supply current, has the on-chip ESD protection devices.

The NJG1155UX2 achieves ultra small mounting area by only two external components and ultra small package that is lead-free and halogen-free 6-pin EPFFP6-X2 package.

■ PACKAGE OUTLINE



NJG1155UX2

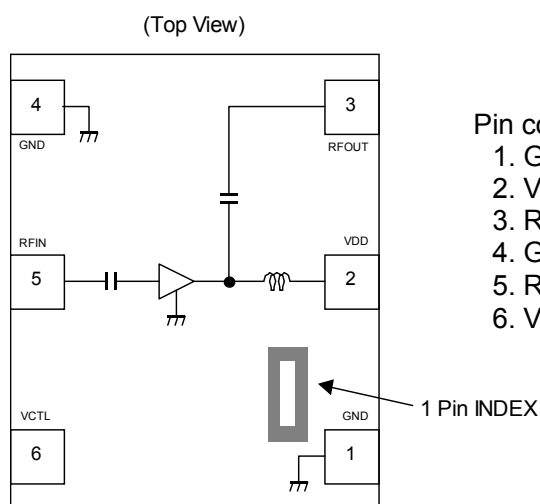
■ APPLICATIONS

GNSS applications, like GPS, Galileo, GLONASS and COMPASS.

■ FEATURES

- Operating frequencies 1550 to 1615MHz
- Low supply voltage 2.8 / 1.8V typ.
- Low current consumption 3.5 / 3.1mA typ. @ $V_{DD}=2.8 / 1.8V$, $V_{CTL}=1.8V$
0.1 μ A typ. @ $V_{DD}=2.8 / 1.8V$, $V_{CTL}=0V$ (Stand-by mode)
- High gain 19.0 / 18.5dB typ. @ $V_{DD}=2.8 / 1.8V$, $V_{CTL}=1.8V$
- Low noise figure 0.75dB typ. @ $V_{DD}=2.8 / 1.8V$, $V_{CTL}=1.8V$
- Ultra small package EPFFP6-X2 (Package size: 1.1mm x 0.7mm x 0.37mm typ.)
- Low external component count 2pcs.
- RoHS compliant and Halogen Free
- MSL1

■ PIN CONFIGURATION



■ TRUTH TABLE

V_{CTL}	LNA mode
H	Active mode
L	Stand-by mode

"H"= $V_{CTL(H)}$, "L"= $V_{CTL(L)}$

Note: Specifications and description listed in this datasheet are subject to change without notice.

NJG1155UX2

■ ABSOLUTE MAXIMUM RATINGS

General conditions: $T_a=+25^{\circ}\text{C}$, $Z_s=Z_l=50\Omega$

PARAMETERS	SYMBOL	CONDITIONS	RATINGS	UNITS
Supply voltage	V_{DD}		5.0	V
Control voltage	V_{CTL}		5.0	V
Input power	P_{IN}	$V_{DD}=2.8\text{V}$	+15	dBm
Power dissipation	P_D	4-layer FR4 PCB without through-hole (101.5mm x 114.5mm), $T_j=150^{\circ}\text{C}$	430	mW
Operating temperature	T_{opr}		-40 to +85	$^{\circ}\text{C}$
Storage temperature	T_{stg}		-55 to +150	$^{\circ}\text{C}$

■ ELECTRICAL CHARACTERISTICS 1 (DC)

General conditions: $T_a=+25^{\circ}\text{C}$, $Z_s=Z_l=50\Omega$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	V_{DD}		1.5	-	3.3	V
Control Voltage (High)	$V_{CTL(H)}$		1.2	1.8	3.3	V
Control Voltage (Low)	$V_{CTL(L)}$		0	0	0.3	V
Supply Current1 (Active mode)	I_{DD1}	$V_{DD}=2.8\text{V}$, $V_{CTL}=1.8\text{V}$	-	3.5	6.0	mA
Supply Current2 (Active mode)	I_{DD2}	$V_{DD}=1.8\text{V}$, $V_{CTL}=1.8\text{V}$	-	3.1	5.5	mA
Supply Current3 (Stand-by mode)	I_{DD3}	$V_{DD}=2.8\text{V}$, $V_{CTL}=0\text{V}$	-	0.1	3.0	μA
Supply Current4 (Stand-by mode)	I_{DD4}	$V_{DD}=1.8\text{V}$, $V_{CTL}=0\text{V}$	-	0.1	3.0	μA
Control Current	I_{CTL}	$V_{CTL}=1.8\text{V}$	-	5.0	12.0	μA

■ ELECTRICAL CHARACTERISTICS 2 (RF, $V_{DD}=2.8V$)

General conditions: $V_{DD}=2.8V$, $V_{CTL}=1.8V$, $f_{RF}=1550$ to $1615MHz$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small Signal Gain1	Gain1	Exclude PCB and connector losses (0.18dB)	16.5	19.0	21.0	dB
Noise Figure1	NF1	Exclude PCB and connector losses (0.08dB)	-	0.75	1.0	dB
Isolation1	ISL1		25.0	35.0	-	dB
Input Power at 1dB Gain Compression Point1	P_{-1dB} (IN)1		-17.0	-12.5	-	dBm
Input 3rd Order Intercept Point1	IIP3_1	$f_1=f_{RF}$, $f_2=f_1\pm 1MHz$, $P_{in}=-30dBm$	-5.0	-1.5	-	dBm
Out of Band Input 3rd Order Intercept Point1	IIP3_OB1	$f_1=1712.7MHz$, $P_{in}=-20dBm$, $f_2=1850MHz$, $P_{in}=-20dBm$, $f_{meas}=1575.4MHz$	-4.0	0.0	-	dBm
RFIN Port Return Loss1	RLi1		6.0	10.0	-	dB
RFOUT Port Return Loss1	RLo1		8.0	12.0	-	dB

■ ELECTRICAL CHARACTERISTICS 3 (RF, $V_{DD}=1.8V$)

General conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $f_{RF}=1550$ to $1615MHz$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small Signal Gain2	Gain2	Exclude PCB and connector losses (0.18dB)	15.0	18.5	21.0	dB
Noise Figure2	NF2	Exclude PCB and connector losses (0.08dB)	-	0.75	1.1	dB
Isolation2	ISL2		25.0	35.0	-	dB
Input Power at 1dB Gain Compression Point2	P_{-1dB} (IN)2		-20.0	-16.0	-	dBm
Input 3rd Order Intercept Point2	IIP3_2	$f_1=f_{RF}$, $f_2=f_1\pm 1MHz$, $P_{in}=-30dBm$	-10.0	-5.0	-	dBm
Out of Band Input 3rd Order Intercept Point2	IIP3_OB2	$f_1=1712.7MHz$, $P_{in}=-20dBm$, $f_2=1850MHz$, $P_{in}=-20dBm$, $f_{meas}=1575.4MHz$	-7.0	-3.0	-	dBm
RF IN Port Return Loss2	RLi2		6.0	10.0	-	dB
RF OUT Port Return Loss2	RLo2		7.0	12.0	-	dB

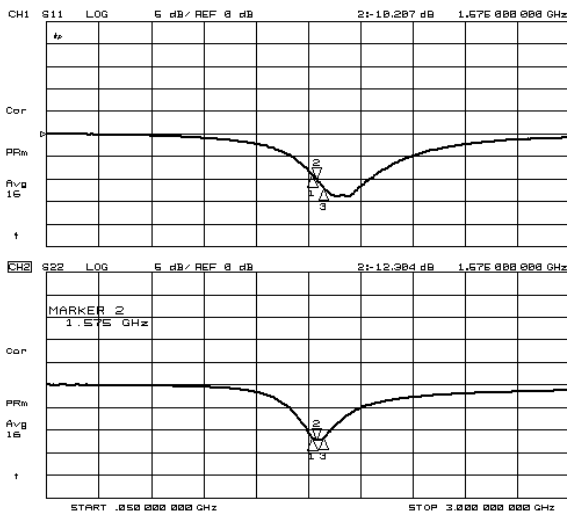
NJG1155UX2

■ TERMINAL INFORMATION

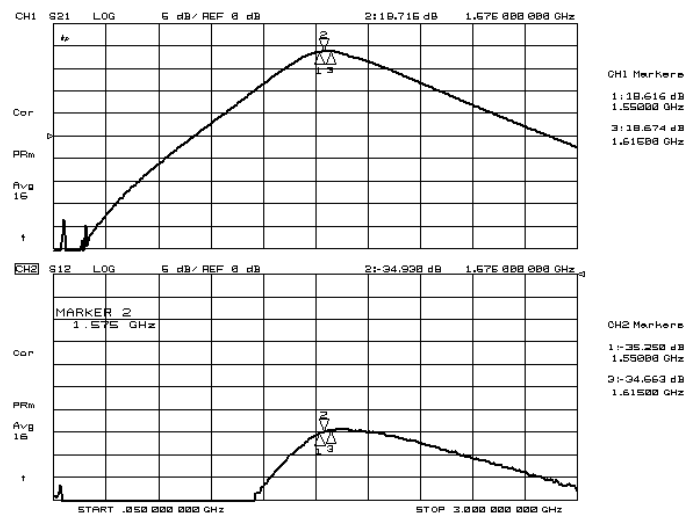
No.	SYMBOL	DESCRIPTION
1	GND	Ground terminal. This terminal should be connected to the ground plane as close as possible for excellent RF performance.
2	VDD	Supply voltage terminal. Please connect bypass capacitor C1 with ground as close as possible.
3	RFOUT	RF output terminal. This terminal requires no DC blocking capacitor since this IC has internal output matching circuit including DC blocking capacitor.
4	GND	Ground terminal. This terminal should be connected to the ground plane as close as possible for excellent RF performance.
5	RFIN	RF input terminal. This terminal requires only a matching inductor L1, and does not require DC blocking capacitor.
6	VCTL	Control voltage terminal.

ELECTRICAL CHARACTERISTICS

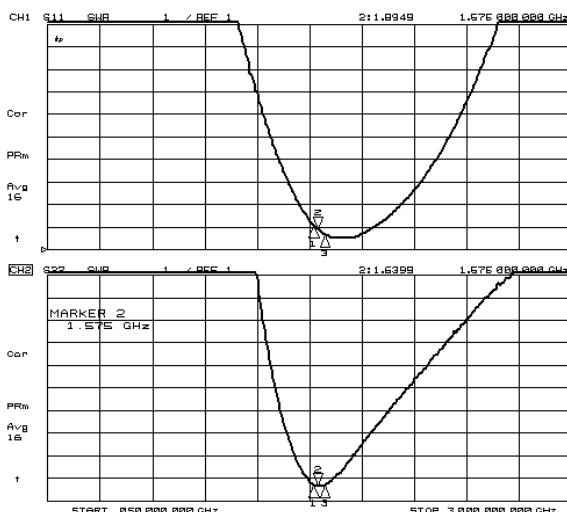
Conditions: $V_{DD}=2.8V$, $V_{CTL}=1.8V$, $T_a=25^\circ C$, $Z_s=Z_l=50\Omega$



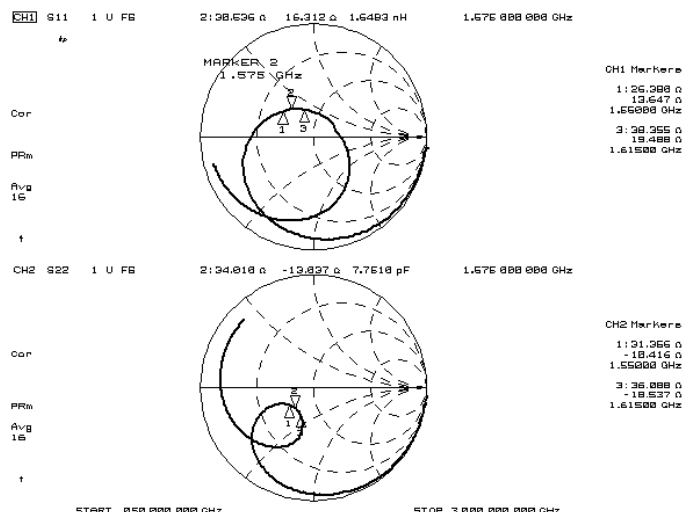
S11, S22



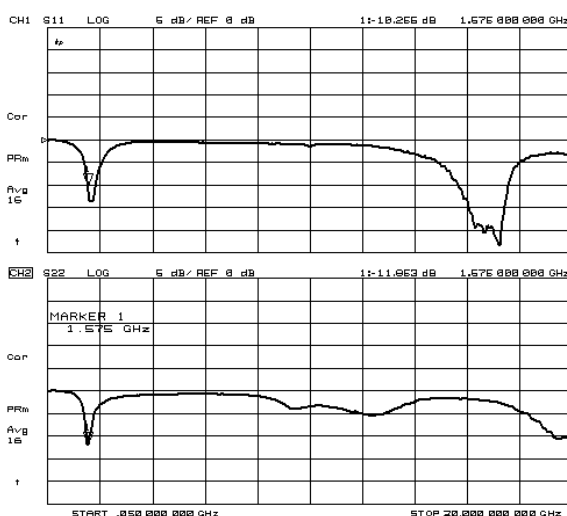
S21, S12



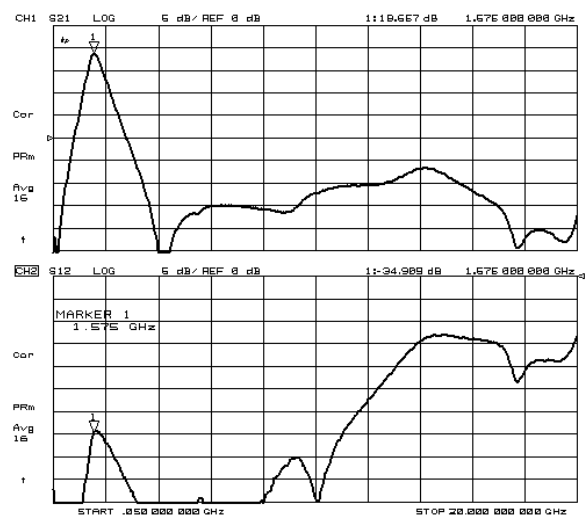
VSWR



Zin, Zout



S11, S22 (f=50M to 20GHz)



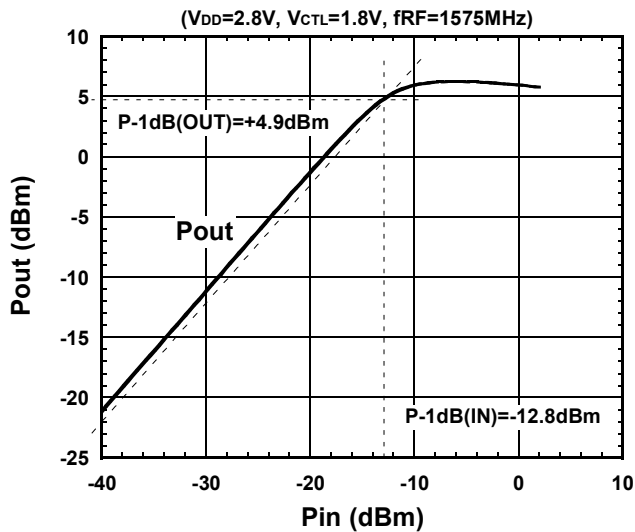
S21, S12 (f=50M to 20GHz)

NJG1155UX2

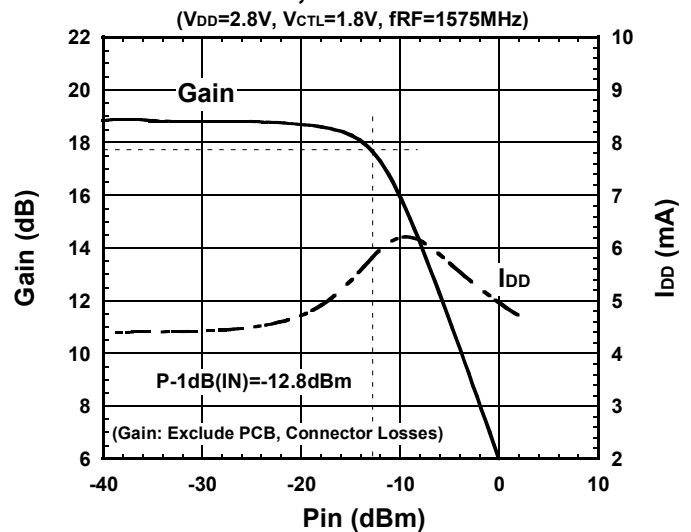
ELECTRICAL CHARACTERISTICS

Conditions: $V_{DD}=2.8V$, $V_{CTL}=1.8V$, $T_a=25^\circ C$, $Z_s=Z_l=50\Omega$

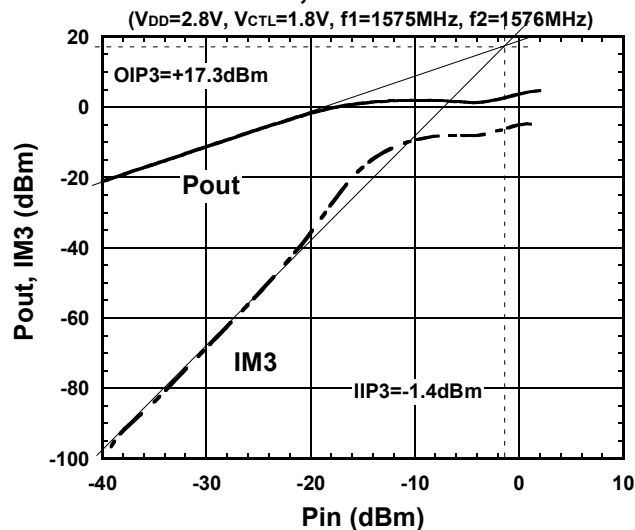
Pout vs. Pin



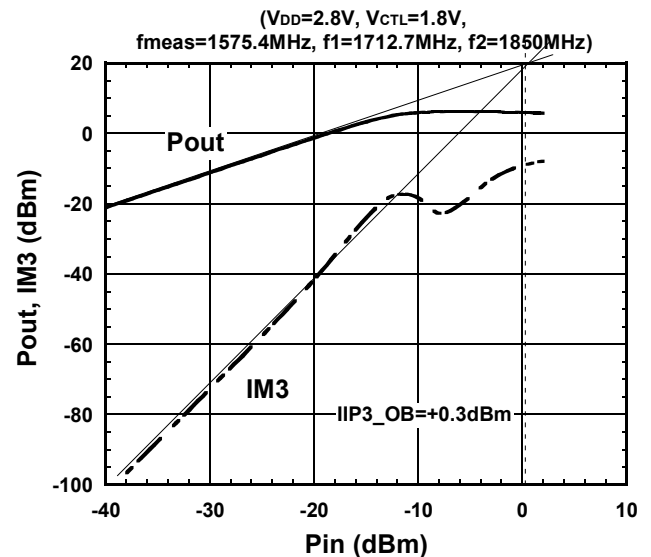
Gain, Idd vs. Pin



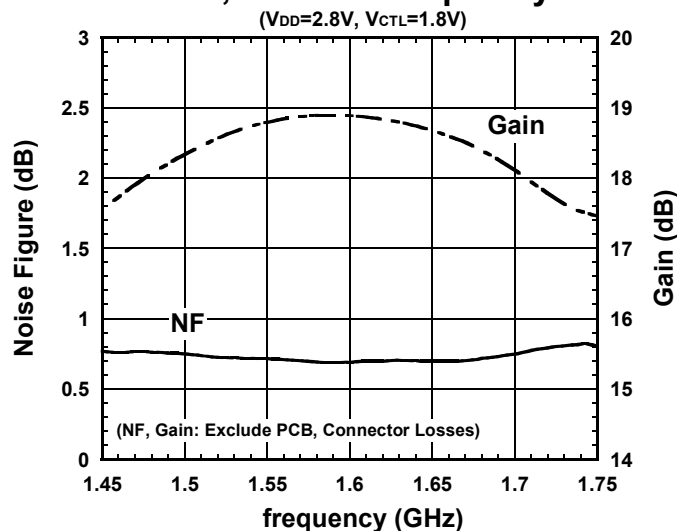
Pout, IM3 vs. Pin



OUT-of-band IIP3



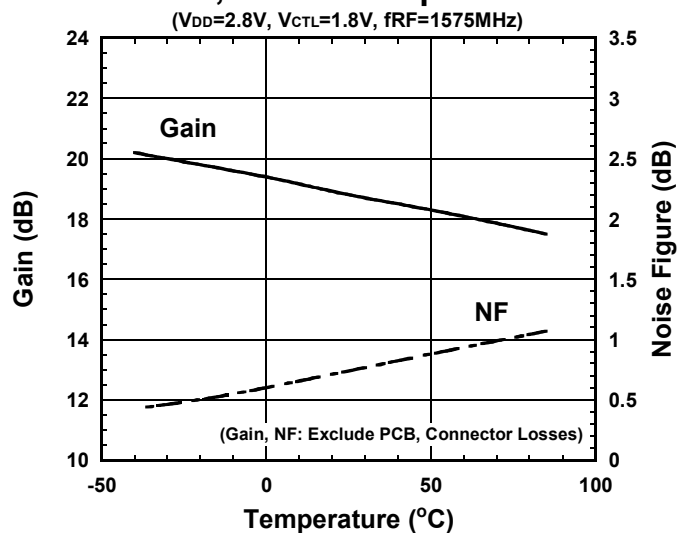
NF, Gain vs. frequency



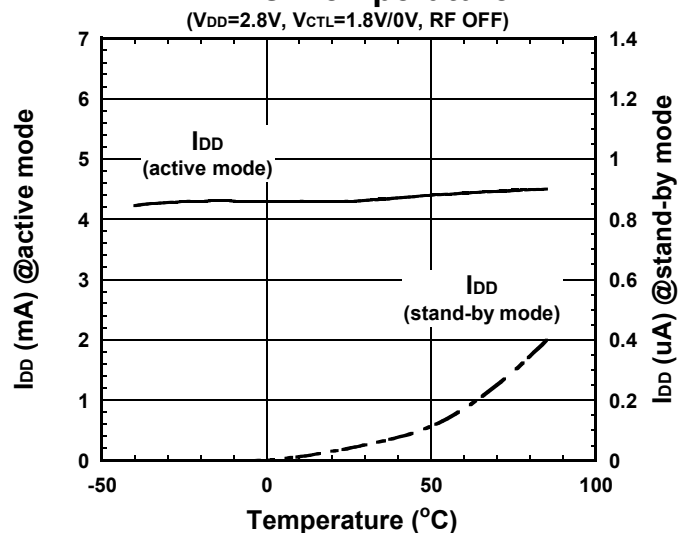
ELECTRICAL CHARACTERISTICS

Conditions: $V_{DD}=2.8V$, $V_{CTL}=1.8V$, $f_{RF}=1575MHz$, $Z_S=Z_L=50\Omega$

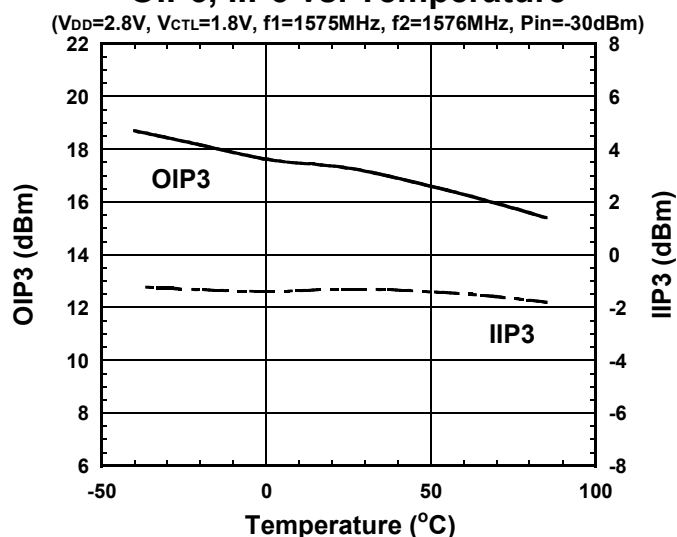
Gain, NF vs. Temperature



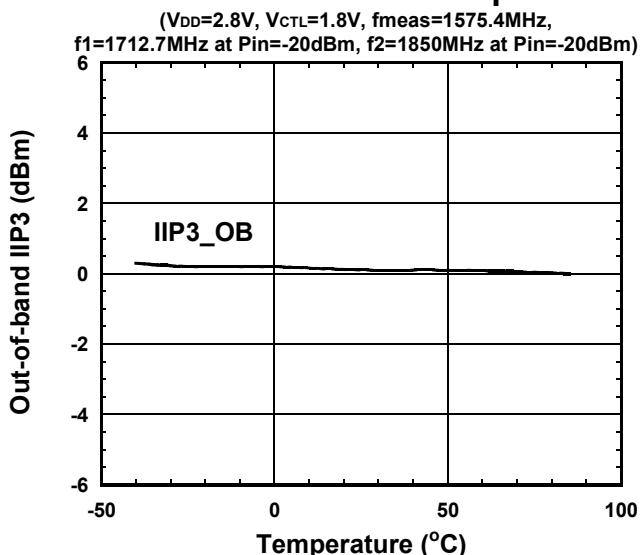
I_{DD} vs. Temperature



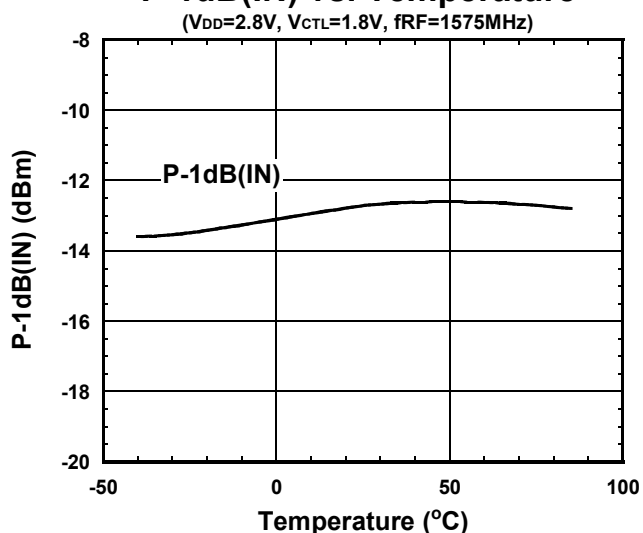
OIP3, IIP3 vs. Temperature



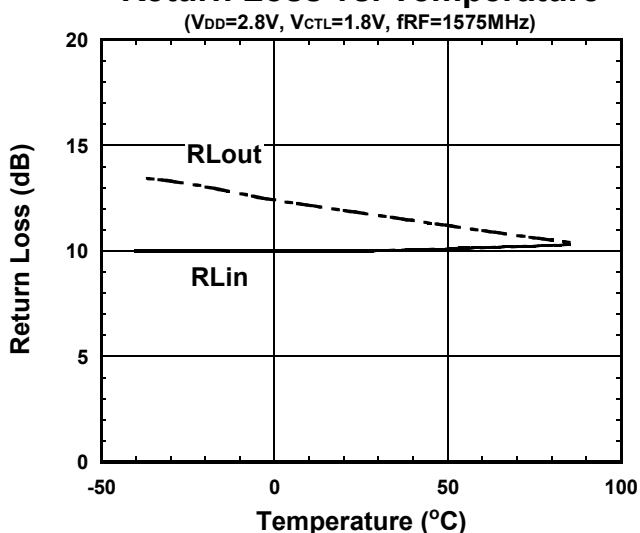
Out-of-band IIP3 vs. Temperature



P-1dB(IN) vs. Temperature

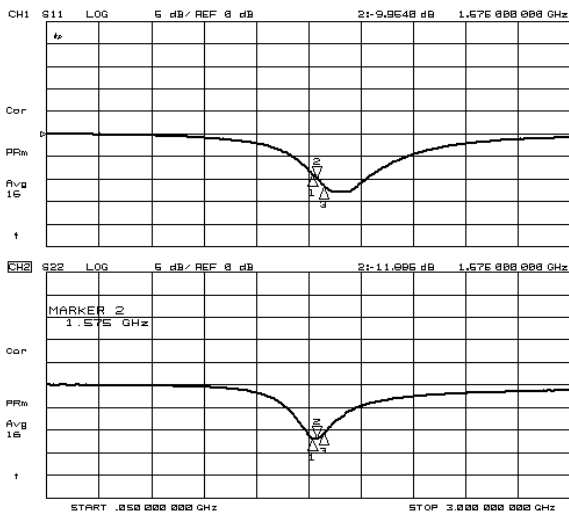


Return Loss vs. Temperature

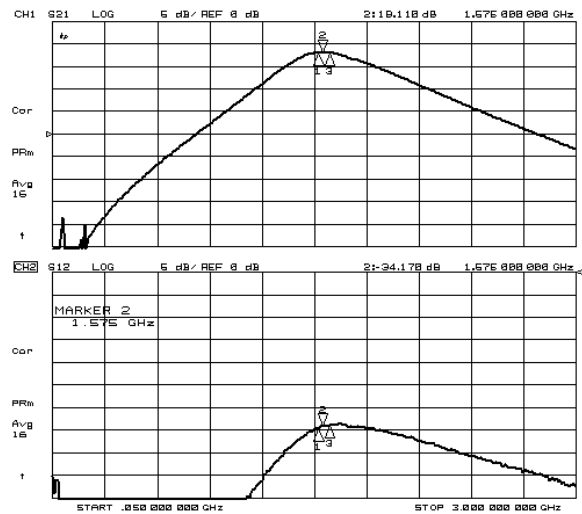


ELECTRICAL CHARACTERISTICS

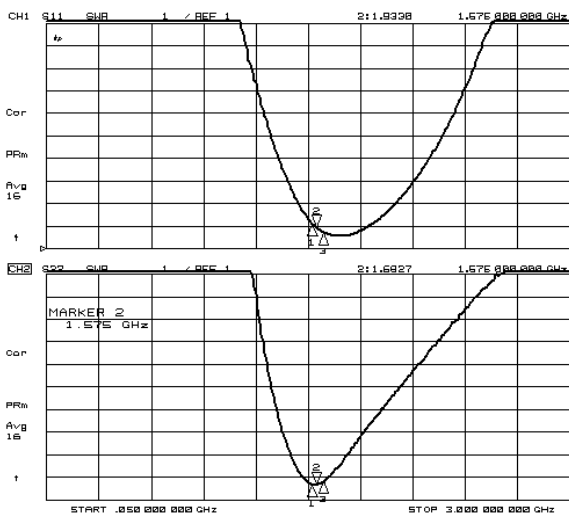
Conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $T_a=25^\circ C$, $Z_s=Z_l=50\Omega$



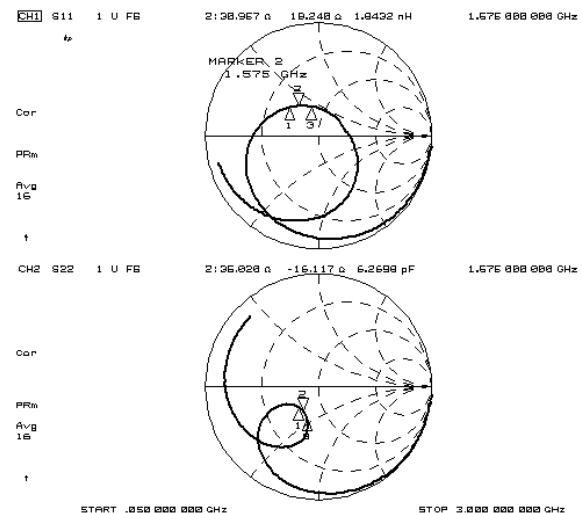
S11, S22



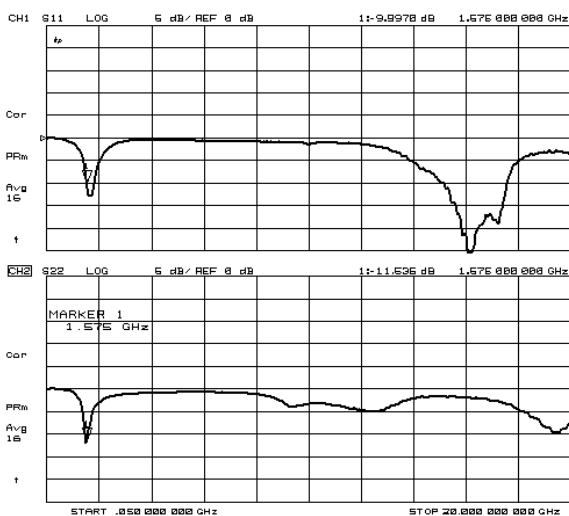
S21, S12



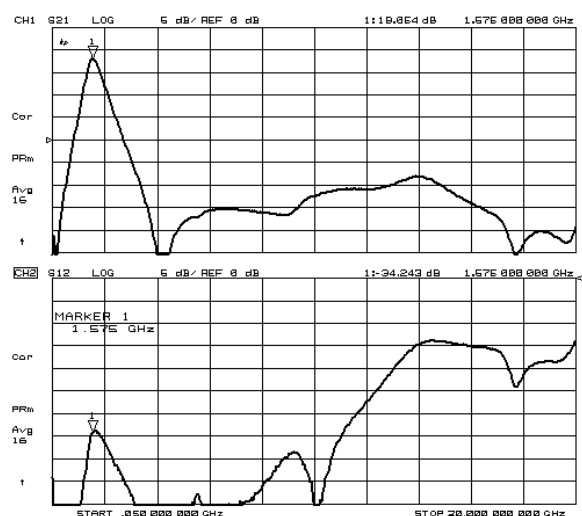
VSWR



Zin, Zout



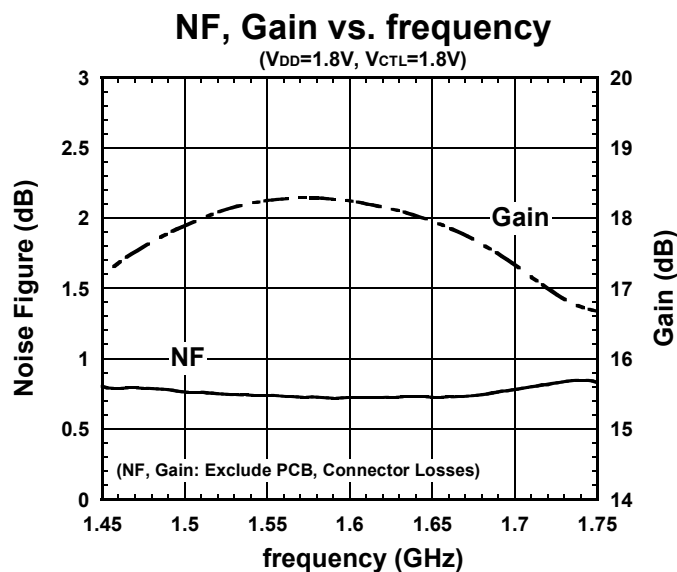
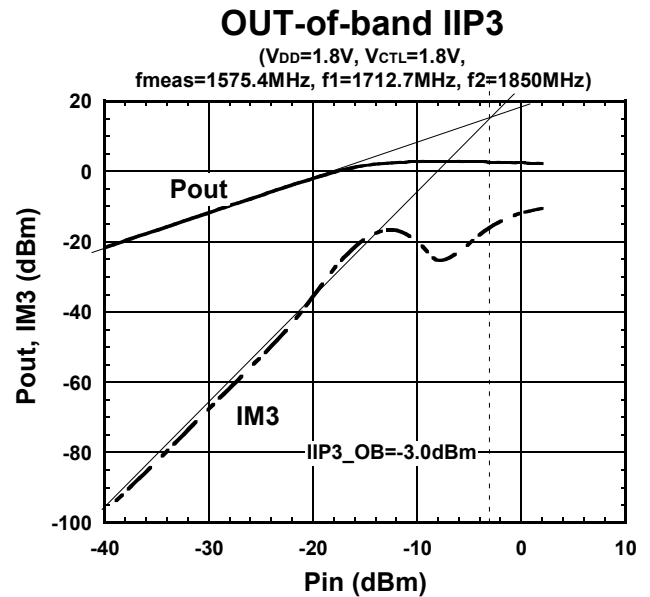
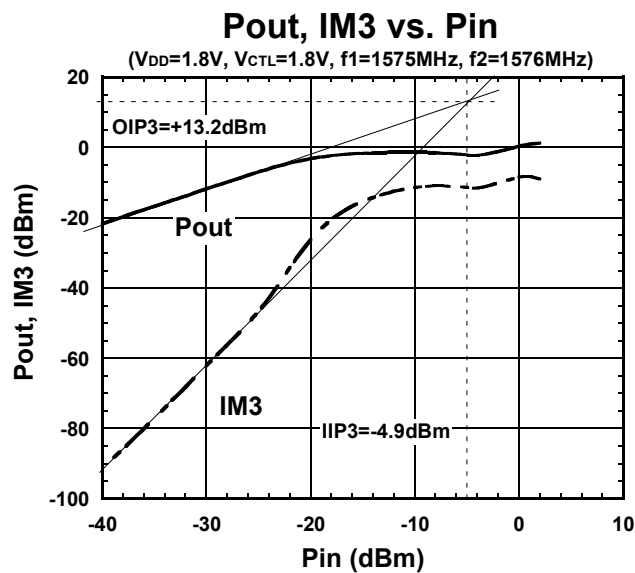
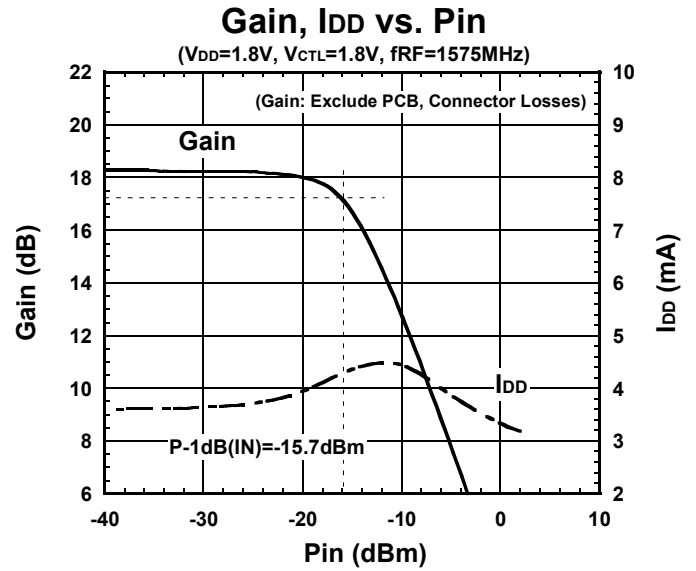
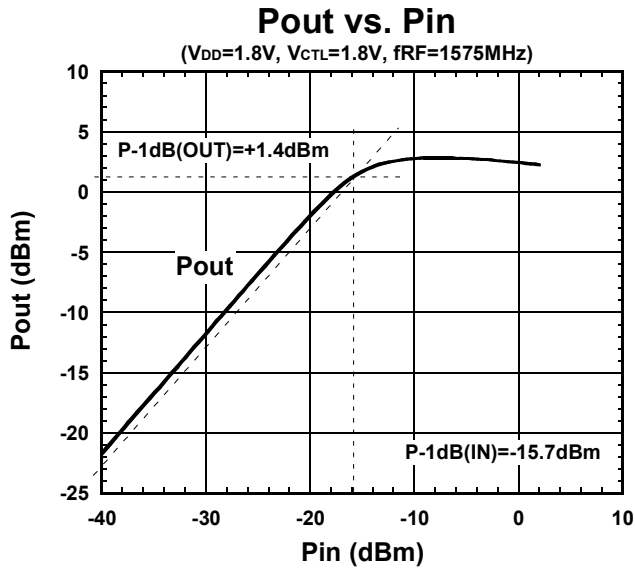
S11, S22 (f=50M to 20GHz)



S21, S12 (f=50M to 20GHz)

ELECTRICAL CHARACTERISTICS

Conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $T_a=25^\circ C$, $Z_s=Z_l=50\Omega$

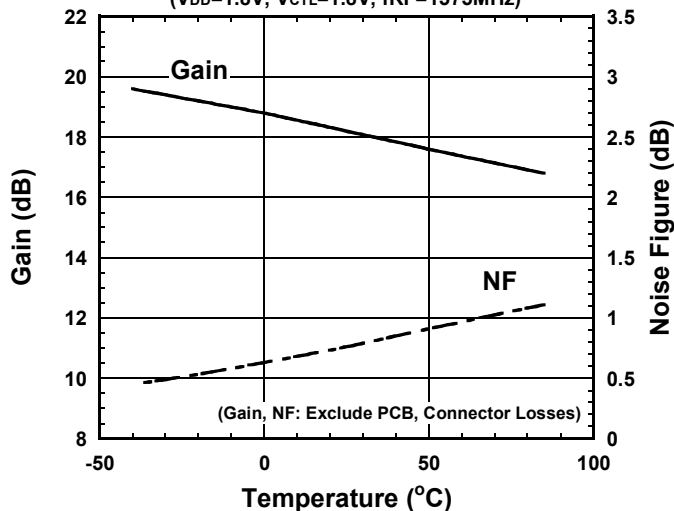


ELECTRICAL CHARACTERISTICS

Conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $f_{RF}=1575MHz$, $Z_S=Z_L=50\Omega$

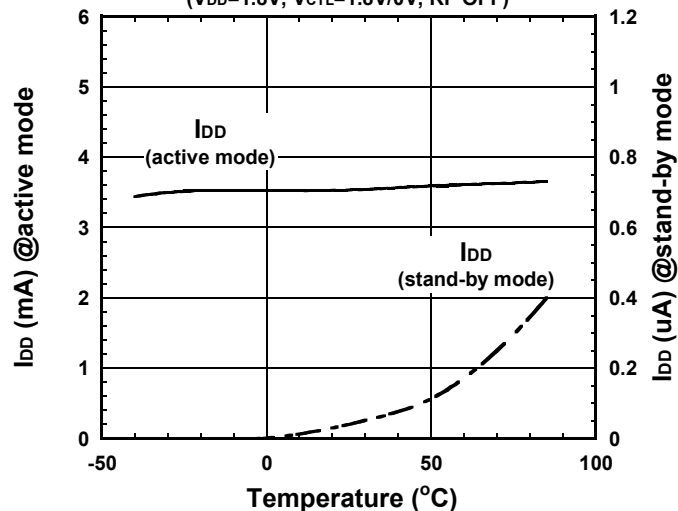
Gain, NF vs. Temperature

($V_{DD}=1.8V$, $V_{CTL}=1.8V$, $f_{RF}=1575MHz$)



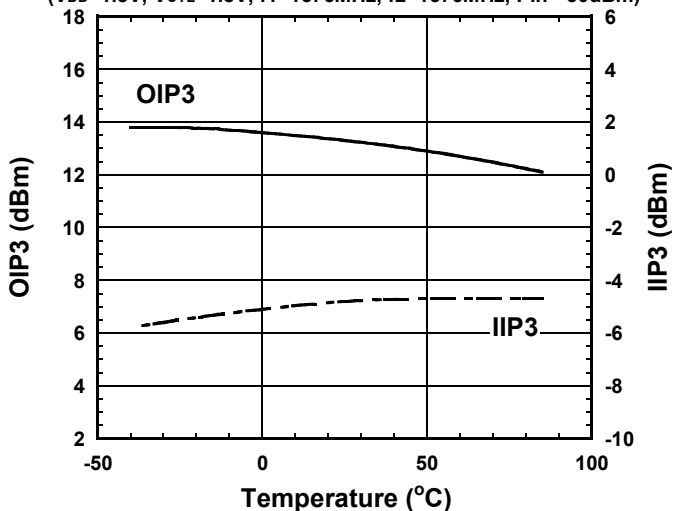
I_{DD} vs. Temperature

($V_{DD}=1.8V$, $V_{CTL}=1.8V/0V$, RF OFF)



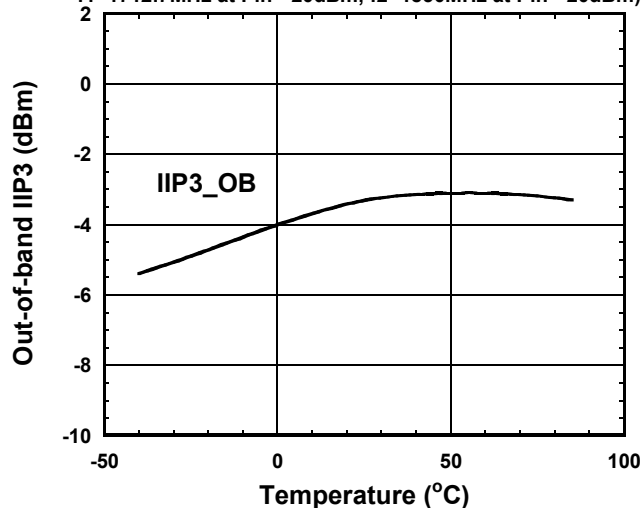
OIP3, IIP3 vs. Temperature

($V_{DD}=1.8V$, $V_{CTL}=1.8V$, $f_1=1575MHz$, $f_2=1576MHz$, $Pin=-30dBm$)



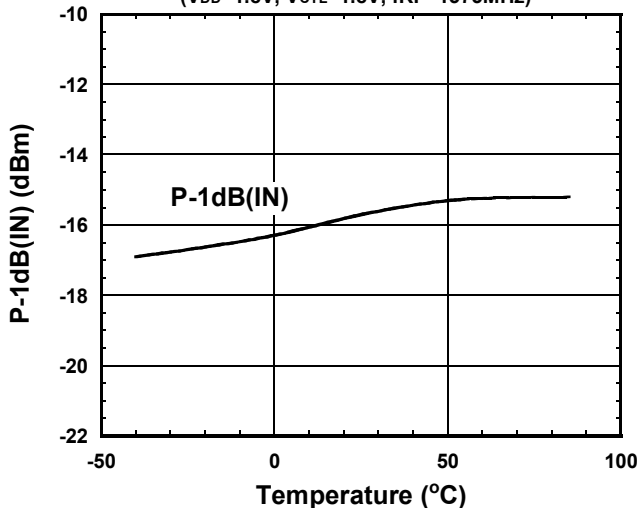
Out-of-band IIP3 vs. Temperature

($V_{DD}=1.8V$, $V_{CTL}=1.8V$, $f_{meas}=1575.4MHz$, $f_1=1712.7MHz$ at $Pin=-20dBm$, $f_2=1850MHz$ at $Pin=-20dBm$)



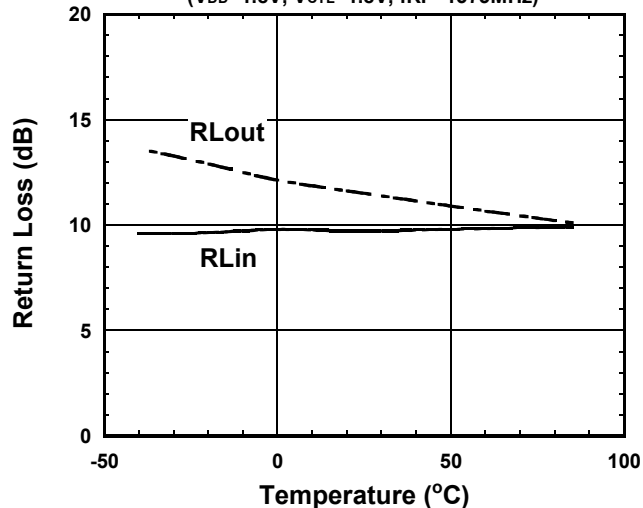
P-1dB(IN) vs. Temperature

($V_{DD}=1.8V$, $V_{CTL}=1.8V$, $f_{RF}=1575MHz$)



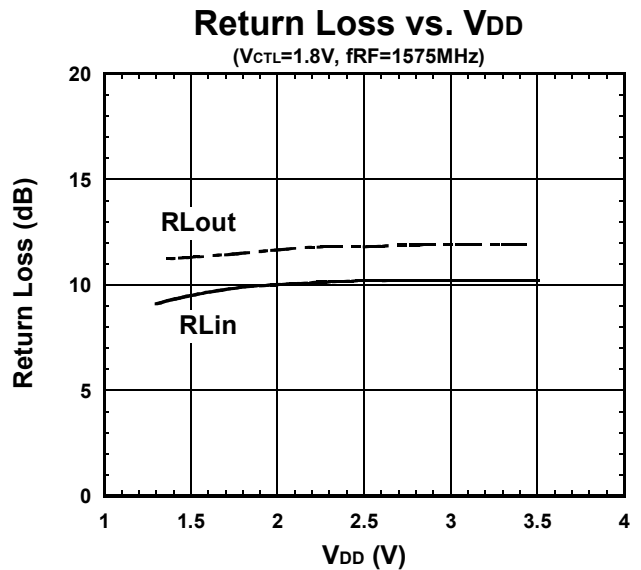
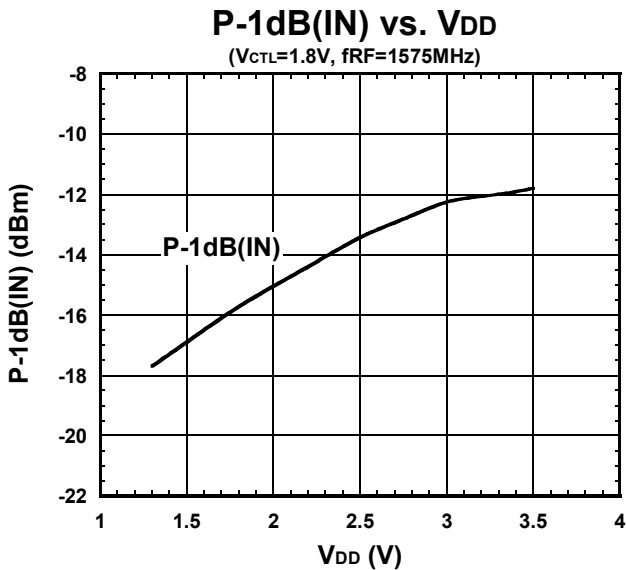
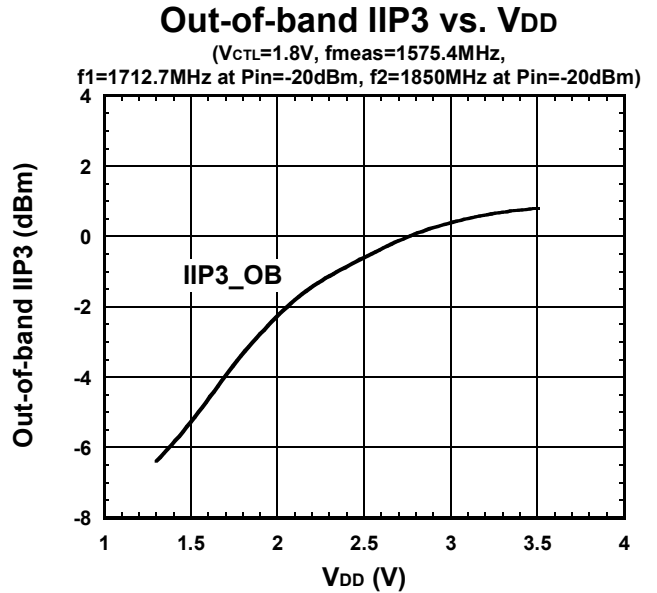
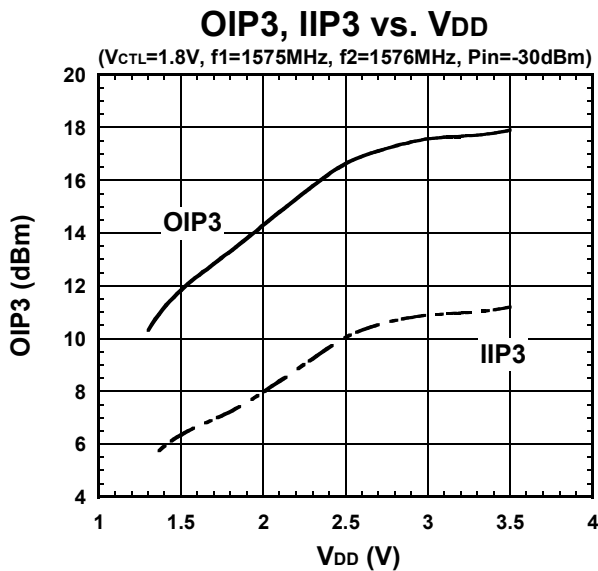
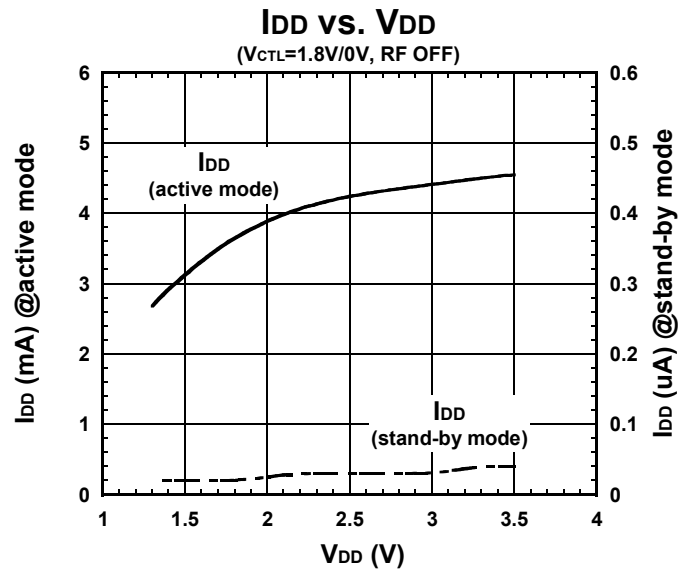
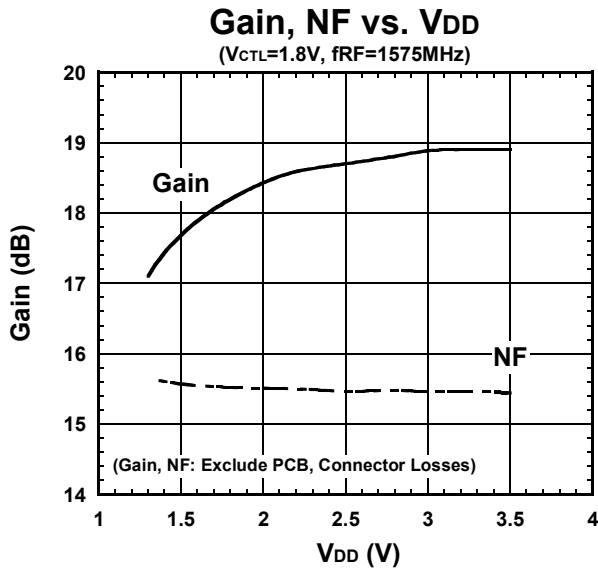
Return Loss vs. Temperature

($V_{DD}=1.8V$, $V_{CTL}=1.8V$, $f_{RF}=1575MHz$)



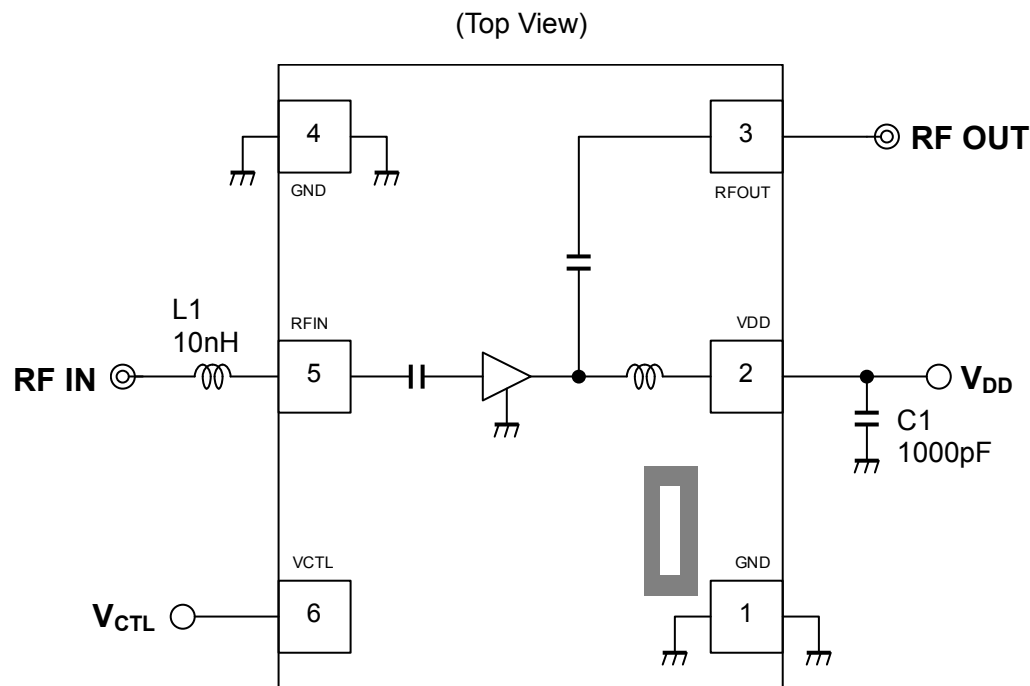
ELECTRICAL CHARACTERISTICS

Conditions: $V_{CTL}=1.8V$, $f_{RF}=1575MHz$, $T_a=25^{\circ}C$, $Z_s=Z_l=50\Omega$



NJG1155UX2

APPLICATION CIRCUIT

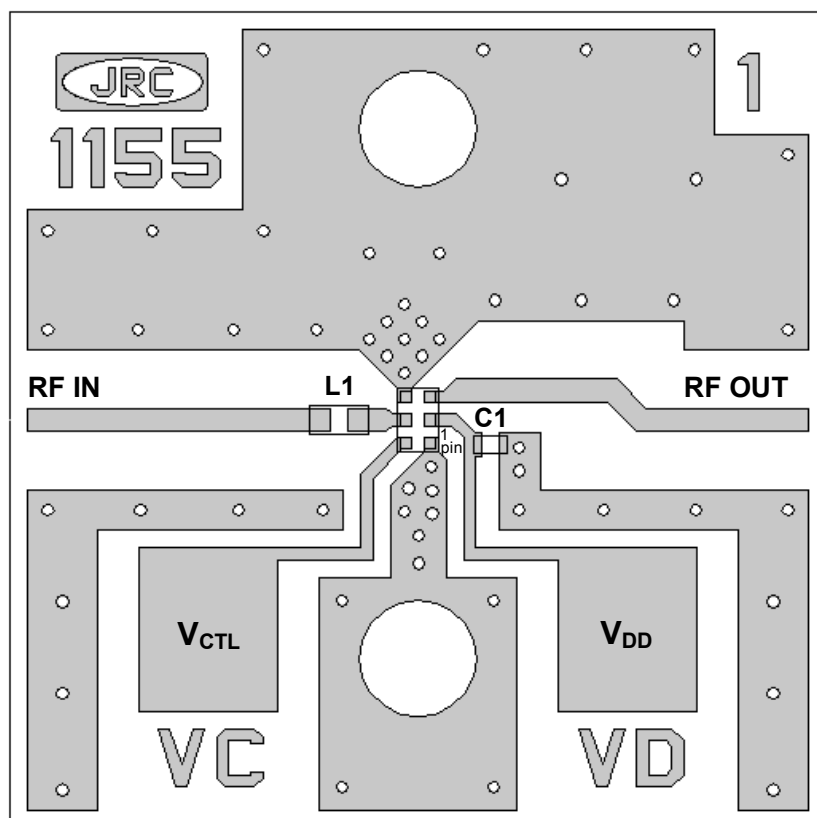


Parts list

Parts ID	Manufacture
L1	LQG15HS Series (MURATA)
C1	GRM03 Series (MURATA)

■ EVALUATION BOARD

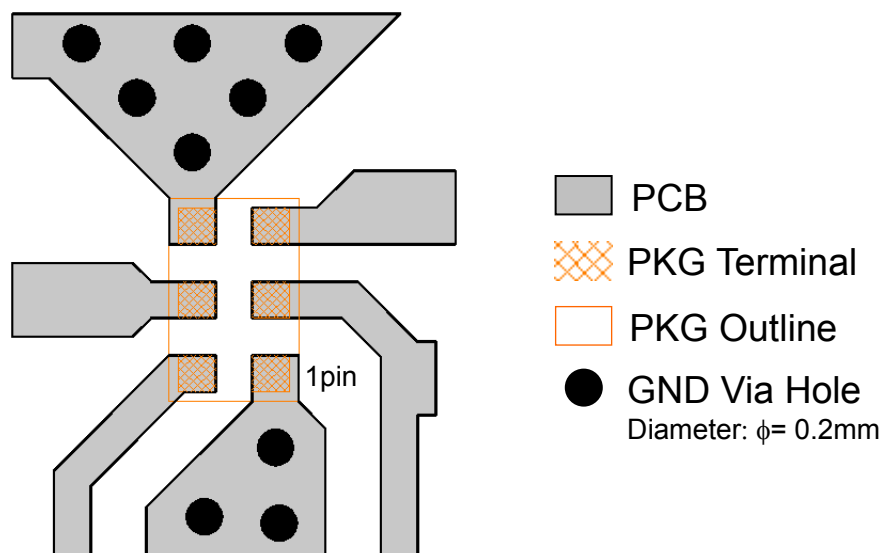
(Top View)



PCB Information

Substrate:	FR-4
Thickness:	0.2mm
Microstrip line width:	0.4mm ($Z_0=50\Omega$)
Size:	14.0mm x 14.0mm

<PCB LAYOUT GUIDELINE>



PRECAUTIONS

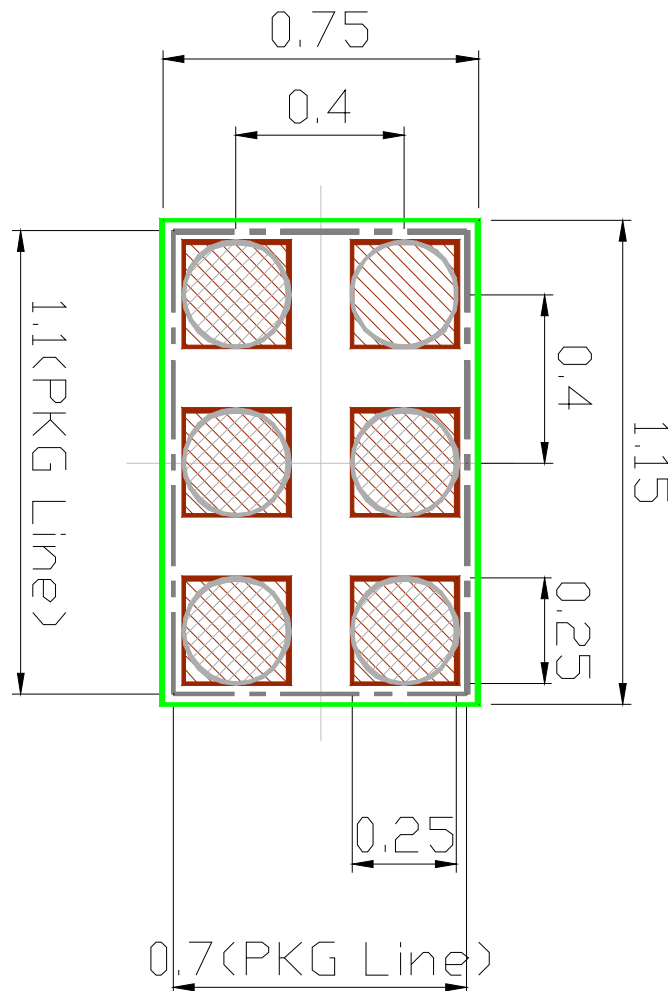
- All external parts should be placed as close as possible to the IC.
- For good RF performance, all GND terminals must be connected to PCB ground plane of substrate, and via-holes for GND should be placed near the IC.

NJG1155UX2

■ RECOMMENDED FOOTPRINT PATTERN (EPFFP6-X2 PACKAGE)

PKG: 1.1mm x 0.7mm
Pin pitch: 0.4mm

 : Land
 : Mask (Open area) *Metal mask thickness : 100μm
 : Resist (Open area)



APPLICATION NOTE FOR ULTRA LOW NOISE FIGURE (Using LQW15A Series high-Q inductor)

This application note shows an example in order to achieve ultra low noise figure (NF).
LQW15A (MURATA) Series inductor is used for this application.

The example of electrical characteristics are shown as follows:

■ ELECTRICAL CHARACTERISTICS (DC)

General conditions: $T_a = +25^{\circ}\text{C}$, $Z_s = Z_l = 50\Omega$

PARAMETER	SYMBOL	CONDITIONS	MEASURED DATA	UNITS
Supply Voltage	V_{DD}		2.8 / 1.8	V
Control Voltage (High)	$V_{CTL(H)}$		1.8	V
Control Voltage (Low)	$V_{CTL(L)}$		0	V
Supply Current1 (Active mode)	I_{DD}	$V_{DD}=2.8\text{V}$, $V_{CTL}=1.8\text{V}$	4.13	mA
Supply Current2 (Active mode)	I_{DD}	$V_{DD}=1.8\text{V}$, $V_{CTL}=1.8\text{V}$	3.43	mA
Supply Current3 (Stand-by mode)	I_{DD}	$V_{DD}=2.8\text{V}$, $V_{CTL}=0\text{V}$	0.1	μA
Supply Current4 (Stand-by mode)	I_{DD}	$V_{DD}=1.8\text{V}$, $V_{CTL}=0\text{V}$	0.0	μA
Control Current	I_{CTL}	$V_{CTL}=1.8\text{V}$	6.6	μA

NJG1155UX2

■ Electrical characteristics (RF, $V_{DD}=2.8V$)

General conditions: $V_{DD}=2.8V$, $V_{CTL}=1.8V$, $f_{RF}=1550$ to $1615MHz$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit

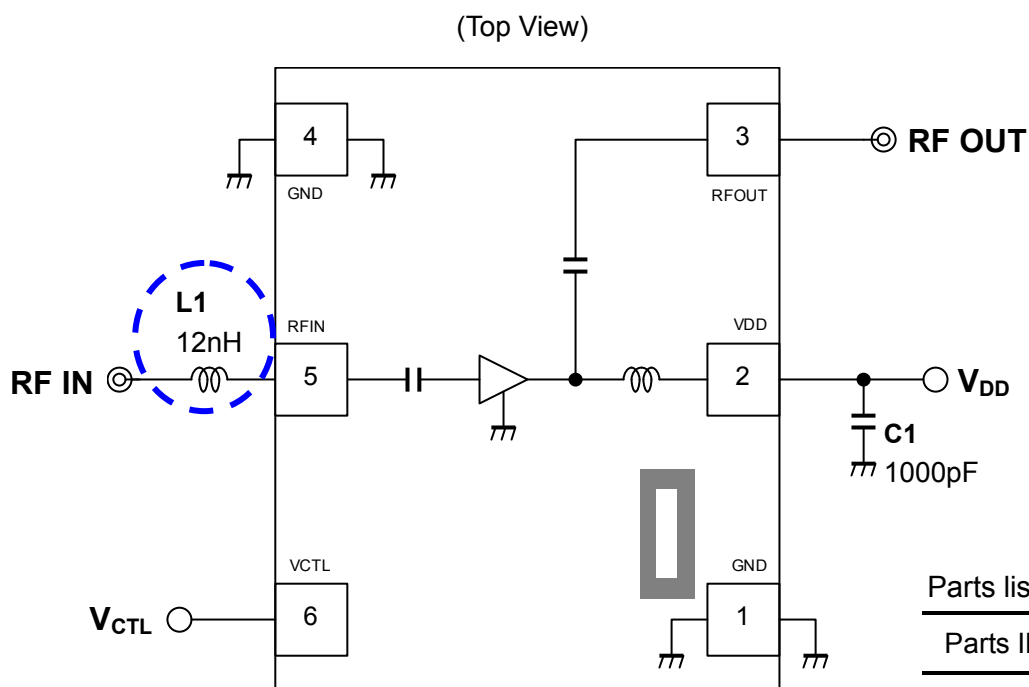
PARAMETER	SYMBOL	CONDITIONS	MEASURED DATA	UNITS
Small Signal Gain	Gain	Exclude PCB and connector losses (0.18dB)	19.0 to 19.1	dB
Noise Figure	NF	Exclude PCB and connector losses (0.08dB)	0.56 to 0.59	dB
Input Power at 1dB Gain Compression Point	$P_{-1dB(IN)}$		-13.6 to -13.2	dBm
Input 3rd Order Intercept Point	IIP3	$f_1=f_{RF}$, $f_2=f_1\pm 1MHz$, $P_{in}=-30dBm$	-2.1	dBm
Out of Band Input 3 rd Order Intercept Point	IIP3_OB	$f_1=1712.7MHz$, $P_{in}=-20dBm$, $f_2=1850MHz$, $P_{in}=-20dBm$, $f_{meas}=1575.4MHz$	-0.4	dBm
RF IN Port Return Loss	RLi		8.8 to 10.3	dB
RF OUT Port Return Loss	RLo		11.1 to 11.8	dB

■ ELECTRICAL CHARACTERISTICS (RF, $V_{DD}=1.8V$)

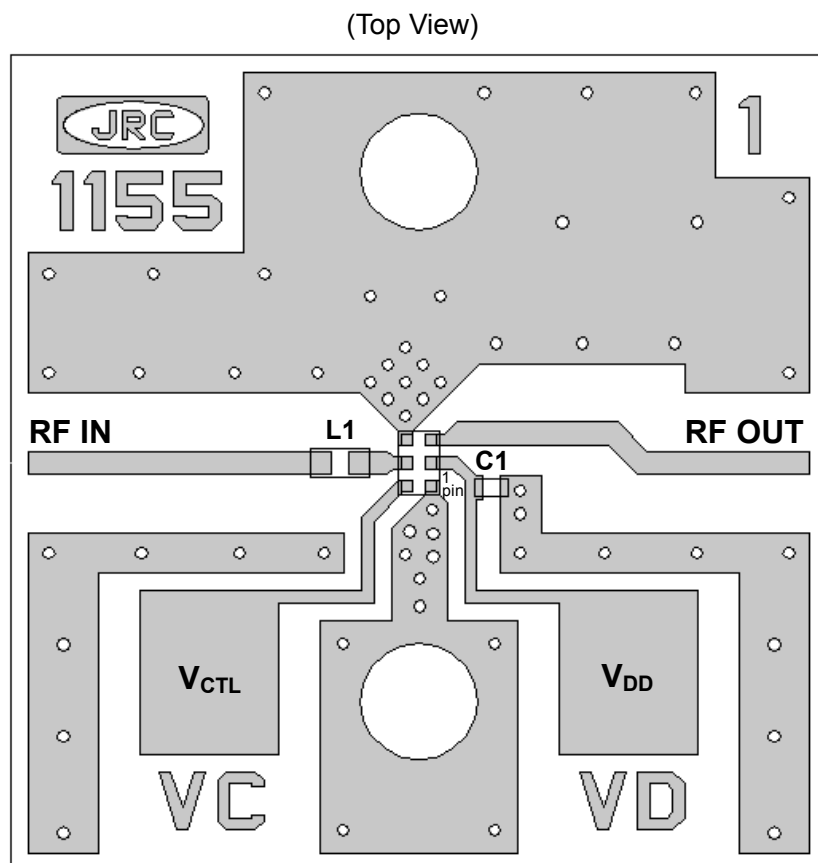
General conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $f_{RF}=1550$ to $1615MHz$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit

PARAMETER	SYMBOL	CONDITIONS	MEASURED DATA	UNITS
Small Signal Gain	Gain	Exclude PCB and connector losses (0.18dB)	18.3 to 18.5	dB
Noise Figure	NF	Exclude PCB and connector losses (0.08dB)	0.59 to 0.62	dB
Input Power at 1dB Gain Compression Point	$P_{-1dB} (IN)$		-16.5 to -16.1	dBm
Input 3rd Order Intercept Point	IIP3	$f_1=f_{RF}$, $f_2=f_1\pm 1MHz$, $P_{in}=-30dBm$	-5.3	dBm
Out of Band Input 3rd Order Intercept Point	IIP3_OB	$f_1=1712.7MHz$, $P_{in}=-20dBm$, $f_2=1850MHz$, $P_{in}=-20dBm$, $f_{meas}=1575.4MHz$	-3.6	dBm
RF IN Port Return Loss	RLi		8.4 to 9.8	dB
RF OUT Port Return Loss	RLo		10.3 to 11.5	dB

APPLICATION CIRCUIT (Using LQW15A Series high-Q inductor)



EVALUATION BOARD (Using LQW15A Series high-Q inductor)



NJG1155UX2

■ NOISE FIGURE MEASUREMENT BLOCK DIAGRAM

Measuring instruments

NF Analyzer : Agilent N8973A
Noise Source : Agilent 346A

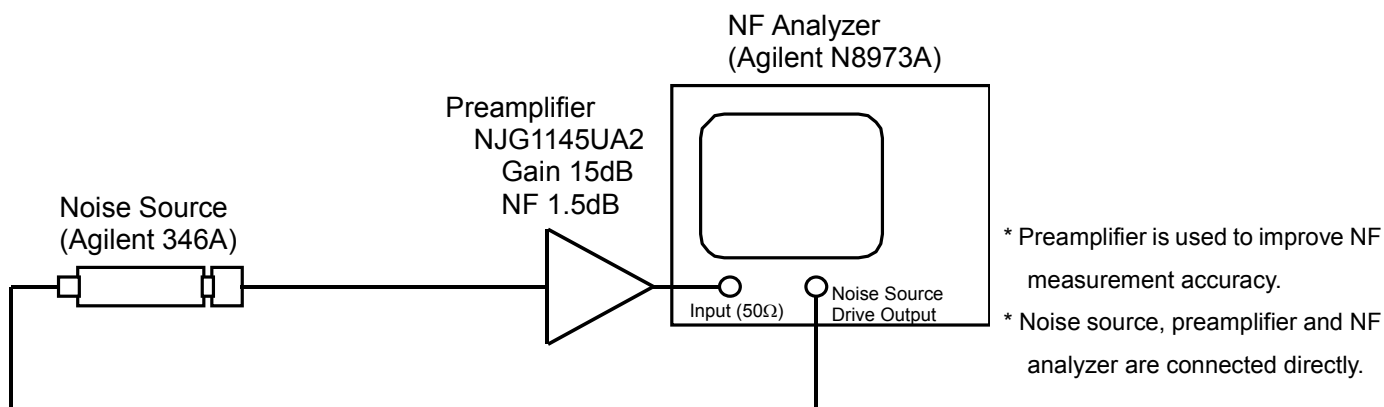
Setting the NF analyzer

Measurement mode form

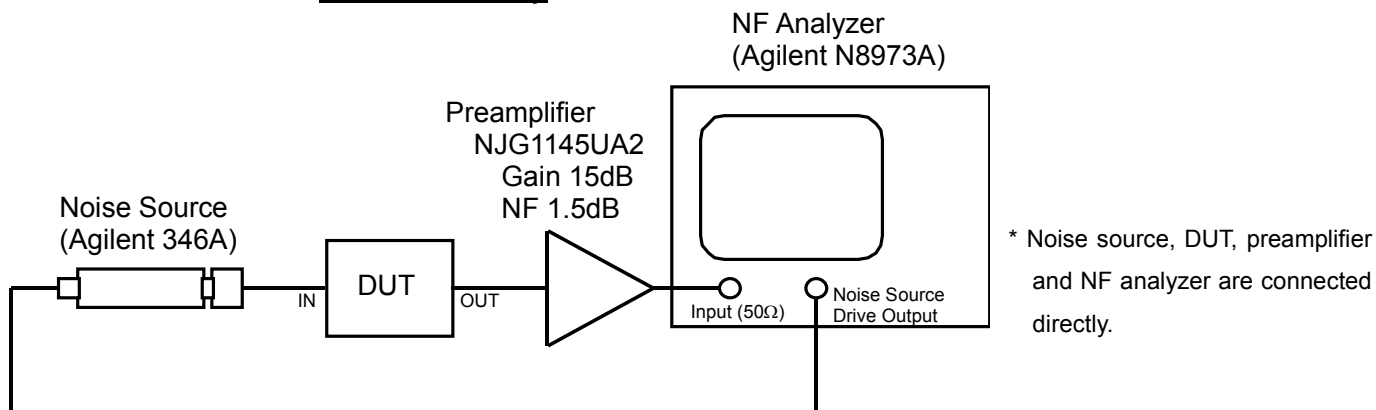
Device under test : Amplifier
System downconverter : off

Mode setup form

Sideband : LSB
Averages : 16
Average mode : Point
Bandwidth : 4MHz
Loss comp : off
Tcold : setting the temperature of noise source (303.15K)



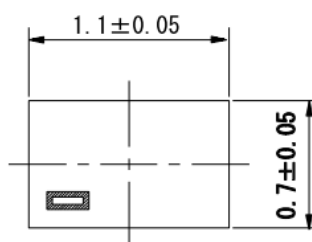
Calibration setup



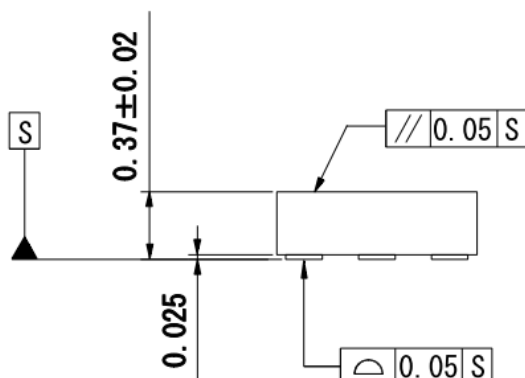
Measurement Setup

■ PACKAGE OUTLINE (EPFFP6-X2)

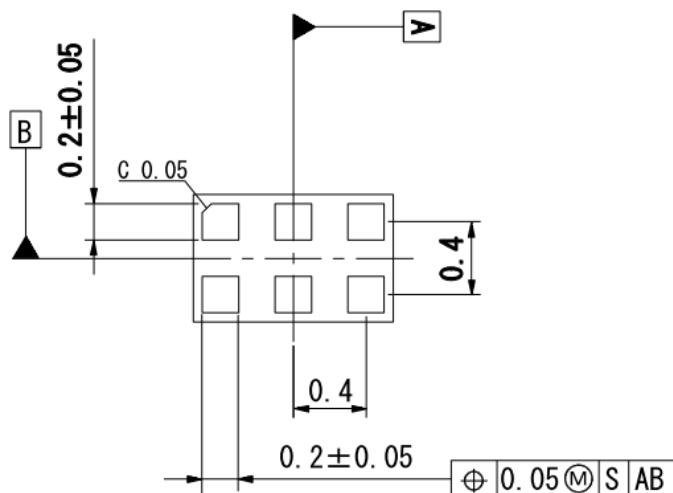
TOP VIEW



SIDE VIEW



BOTTOM VIEW



Unit	: mm
Substrate	: FR4
Terminal treat	: Au
Molding material	: Epoxy resin
Weight (typ.)	: 0.7mg

Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

[CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions.

The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

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- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
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- Входной контроль качества.
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- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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